

HMC996* PRODUCT PAGE QUICK LINKS

Last Content Update: 02/23/2017

COMPARABLE PARTS

View a parametric search of comparable parts.

EVALUATION KITS

- HMC996LP4E Evaluation Board

DOCUMENTATION

Data Sheet

- HMC996 Data Sheet

TOOLS AND SIMULATIONS

- HMC996 S-Parameter

REFERENCE MATERIALS

Quality Documentation

- Package/Assembly Qualification Test Report: LP3, LP4, LP5 & LP5G (QTR: 2014-00145)
- Semiconductor Qualification Test Report: PHEMT-F (QTR: 2013-00269)

DESIGN RESOURCES

- HMC996 Material Declaration
- PCN-PDN Information
- Quality And Reliability
- Symbols and Footprints

DISCUSSIONS

View all HMC996 EngineerZone Discussions.

SAMPLE AND BUY

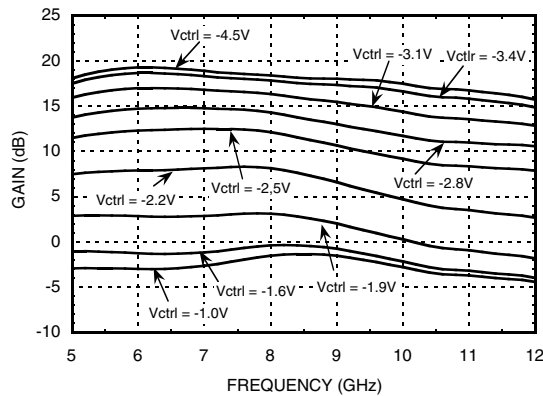
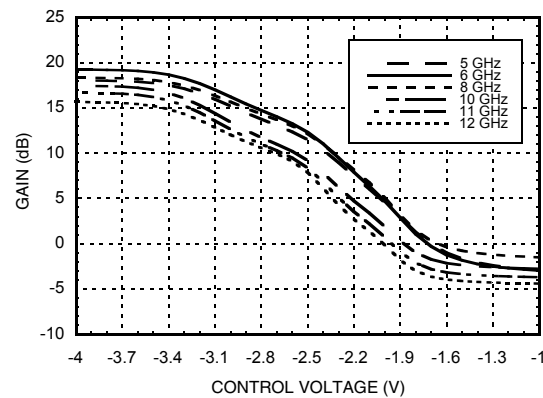
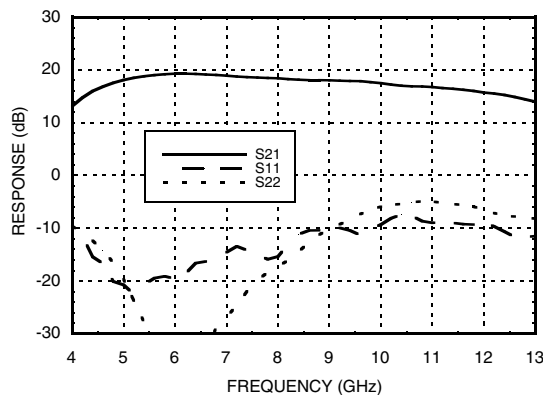
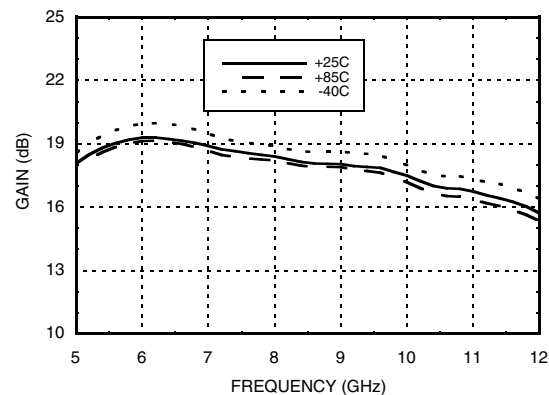
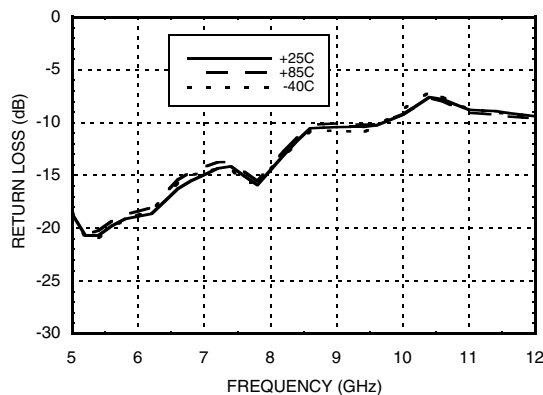
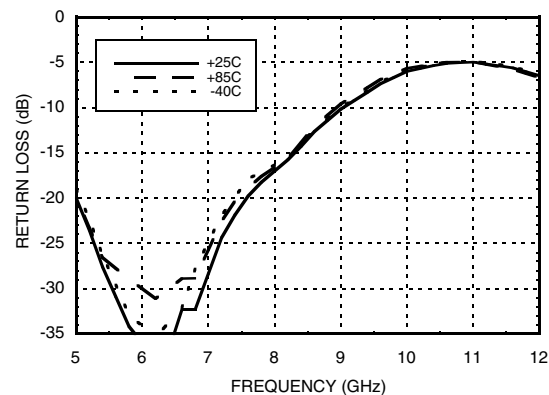
Visit the product page to see pricing options.

TECHNICAL SUPPORT

Submit a technical question or find your regional support number.

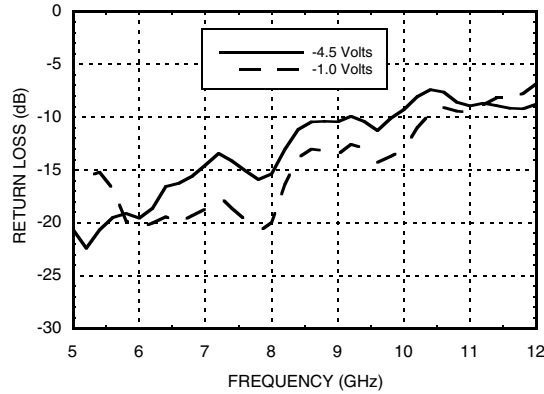
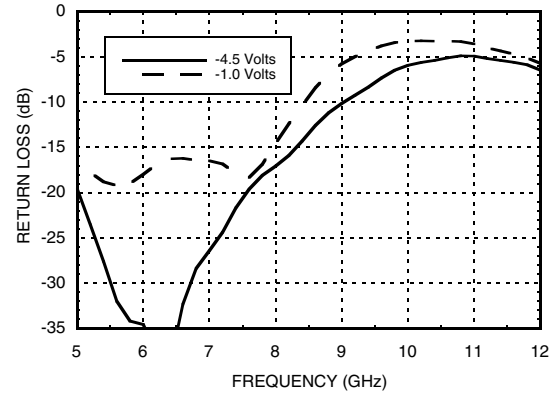
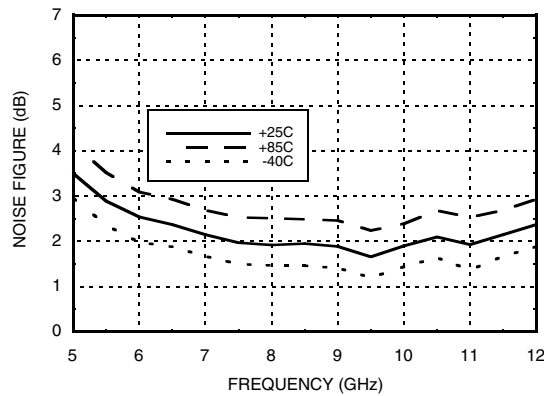
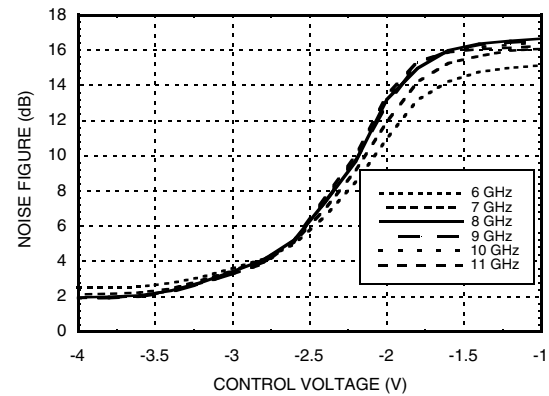
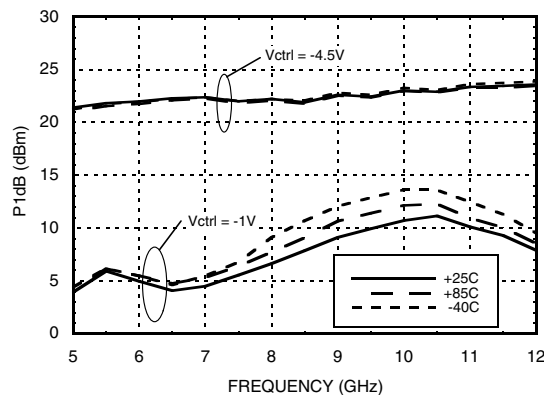
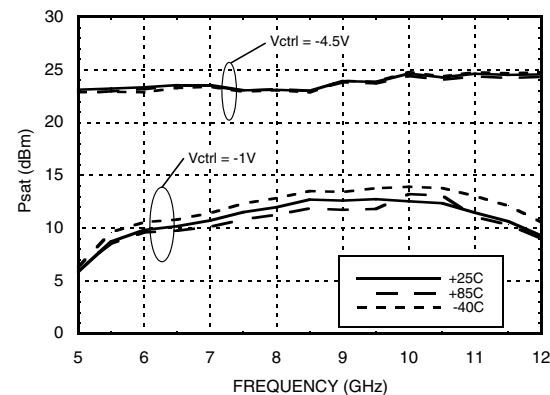
DOCUMENT FEEDBACK

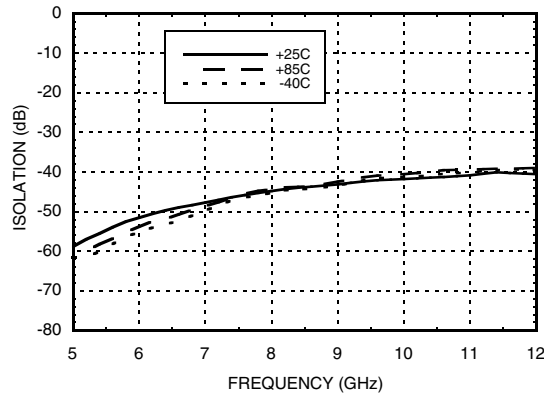
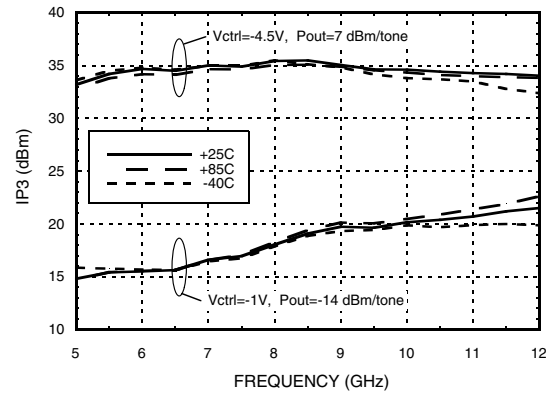
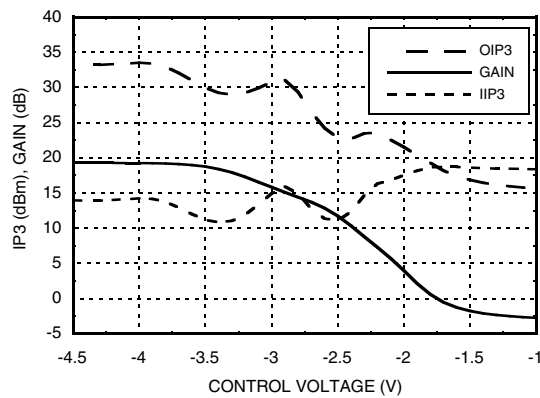
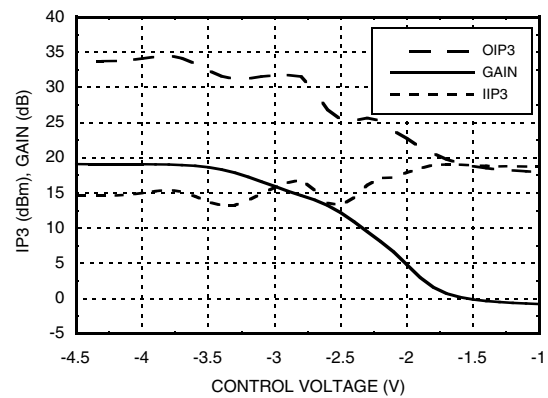
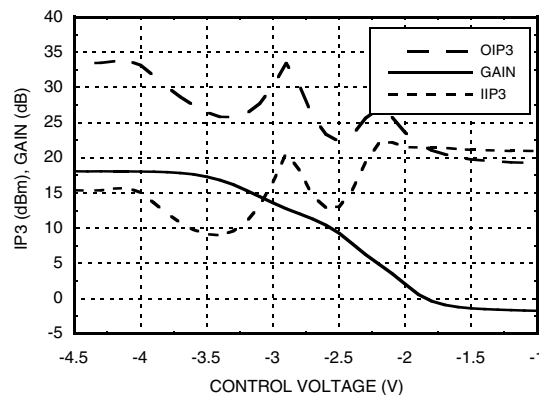
Submit feedback for this data sheet.

**VARIABLE GAIN AMPLIFIER
5 - 12 GHz**
Gain vs. Control Voltage Range

Gain vs. Control Voltage

Broadband Gain & Return Loss

Gain vs. Temperature

Input Return Loss vs. Temperature

Output Return Loss vs. Temperature




VARIABLE GAIN AMPLIFIER **5 - 12 GHz**

**Input Return Loss @ Control Voltage
Extreme**

**Output Return Loss @ Control Voltage
Extreme**

Noise Figure vs. Temperature

Noise Figure vs. Control Voltage

P1dB vs. Temperature

Psat vs. Temperature



**VARIABLE GAIN AMPLIFIER
5 - 12 GHz**
Reverse Isolation vs. Temperature

Output IP3 vs. Temperature

IP3 and Gain @ 6 GHz, $P_{in} = -10$ dBm

IP3 and Gain @ 8 GHz, $P_{in} = -10$ dBm

IP3 and Gain @ 10 GHz, $P_{in} = -10$ dBm




VARIABLE GAIN AMPLIFIER 5 - 12 GHz

Absolute Maximum Ratings

Drain Bias Voltage (Vdd1, 2)	+5.5V
Gate Bias Voltage (Vgg1, 2)	-3 to 0V
Gain Control Voltage (Vctrl)	-5 to 0V
RF Power Input	+20 dBm
Channel Temperature	175 °C
Continuous P _{diss} (T = 85 °C) (derate 11.5 mW/°C above 85 °C) [1]	1.03 W
Thermal Resistance (Channel to ground paddle)	86.7 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C
ESD Sensitivity (HBM)	Class 0 Passed 150V

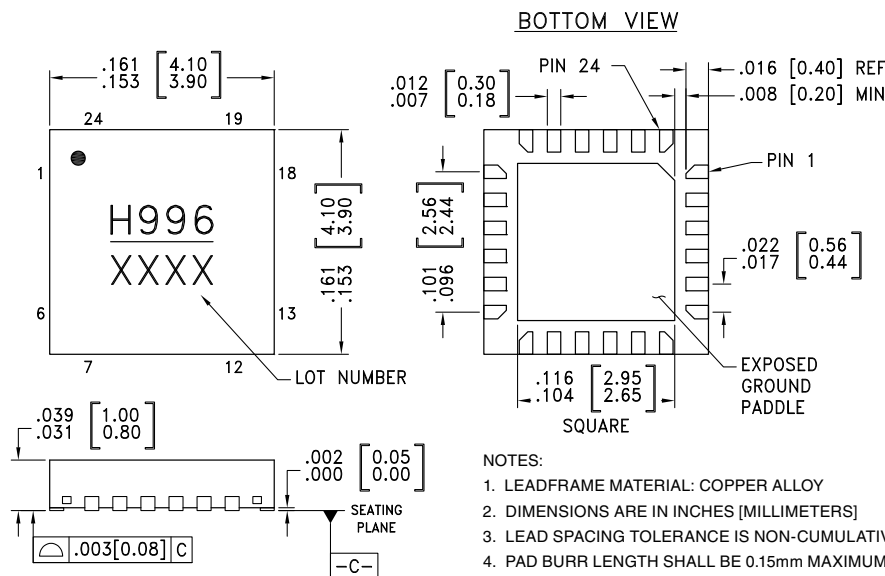
Bias Voltage

Vdd1,2(V)	Idd Total (mA)
+5V	120 mA
Vgg1,2 (V)	Igg Total (mA)
0V to -2V	<0.1 mA



**ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS**

Outline Drawing



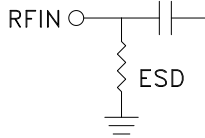
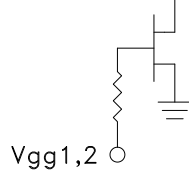
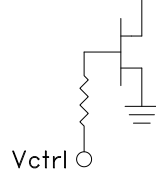
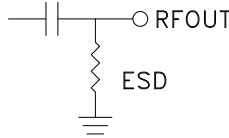
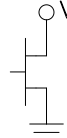
Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking [2]
HMC996LP4E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 [1]	H996 XXXX

[1] Max peak reflow temperature of 260 °C

[2] 4-Digit lot number XXXX

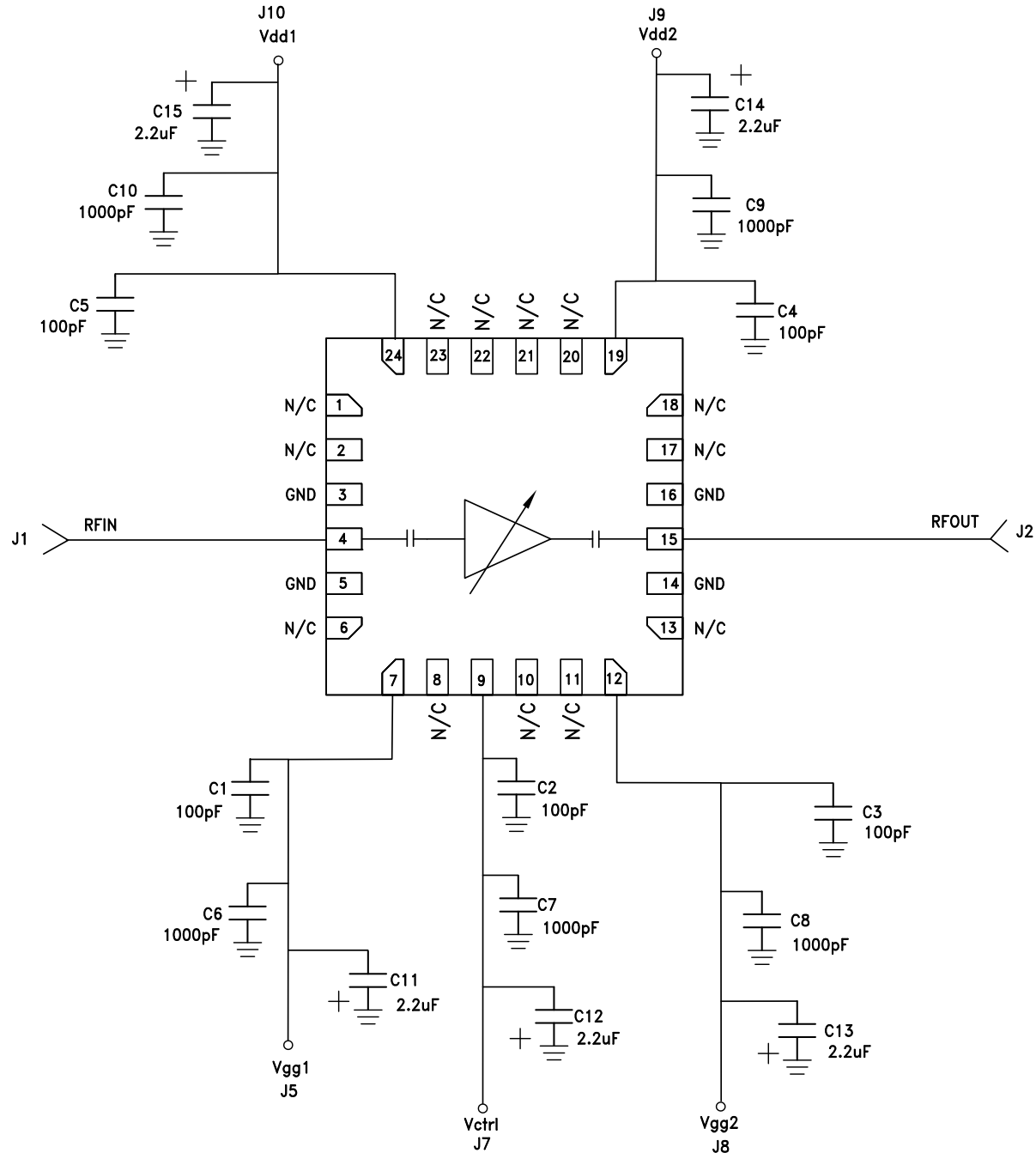

VARIABLE GAIN AMPLIFIER
5 - 12 GHz
Pin Descriptions

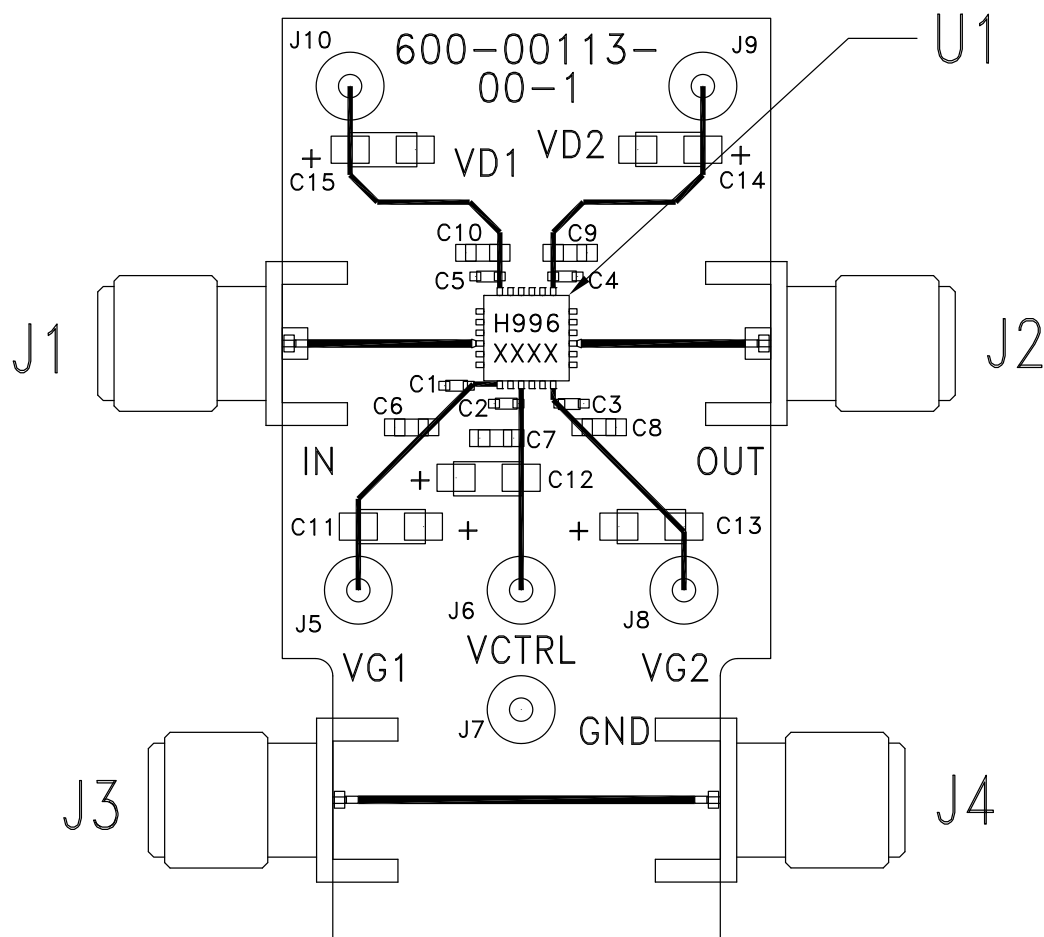
Pin Number	Function	Description	Interface Schematic
1, 2, 6, 8, 10, 11, 13, 17, 18, 20, 21, 22, 23	N/C	The pins are not connected internally; however all data shown herein was measured with these pins connected to RF/DC ground externally	
3, 5, 14, 16	GND	These pins and exposed ground paddle must be connected to RF/DC ground.	
4	RFIN	This pad is AC coupled and matched to 50 Ohm.	
7, 12	Vgg1, 2	Gate control for amplifier. Adjust voltage to achieve typical I _{dd} . Please follow "MMIC Amplifier Biasing Procedure" application note.	
9	Vctrl	Gain control Voltage for the amplifier. See assembly diagram for required external components.	
15	RFOUT	This pad is AC coupled and matched to 50 Ohm.	
19, 24	Vdd1, 2	Drain Bias Voltage for the amplifier. See assembly diagram for required external components	



**VARIABLE GAIN AMPLIFIER
5 - 12 GHz**

Application Circuit




**VARIABLE GAIN AMPLIFIER
5 - 12 GHz**
Evaluation PCB

List of Materials for Evaluation PCB
EVAL01-HMC996LP4E [1]

Item	Description
J1, J4	PCB Mount SMA RF Connectors
J5 - J10	DC Pin
C1 - C5	100 pF Capacitor, 0402 Pkg.
C6 - C10	1000 pF Capacitor, 0603 Pkg.
C11 - C15	2.2 μ F Capacitor, CASE A
U1	HMC996LP4E Variable Gain Amplifier
PCB [2]	600-00113-00 Evaluation PCB

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Arlon 25FR

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hit-tite upon request.